

Sum 13

COMMUNICATIONS IN PHYSICS

ISSN 0868 - 3166

Published by
VIETNAMESE ACADEMY OF SCIENCE AND TECHNOLOGY

SUPPLEMENT

PROCEEDINGS OF 30TH NATIONAL CONFERENCE OF THEORETICAL PHYSICS

Contents

	Page
Phung Phuong Vu, Huynh Thanh Duc, and Tran Thoai Duy Bao - Fermi-Edge Singularities in Highly Excited Quantum Wires in Magnetic Field	1-6
Hoang Zung, Nguyen Trung Hai, Bui Hoang Lan Khanh, Diep Quang Vinh, Nguyen Ha Hung Chuong, Nguyen Van Khoe, Daniel Dominguez, and Mai Suan Li - Critical Exponents in Vortex Glass Transition of Three-dimensional XY Model	7-10
Nguyen Van Hung, Phung Quoc Bao, Nguyen Ba Duc, and Le Hai Hung - Debye-Waller Factor and Correlation Effects in XAFS of Cubic Crystals	11-17
Tran Huu Phat, Nguyen Tuan Anh, Le Viet Hoa, and Phan Hong Lien - On The Fermi Con- densation (I)	17-22
Phinh Nhu Thao, Phan Phuoc Ngoc Hoang, S. Katayama, K. Tomizawa, and Dang Thanh Duong - Monte Carlo Analysis of THz Radiation by Coherent LO Phonon Oscillations in Some GaAs Devices under High Electric Fields	23-28
Nguyen Huyen Tung, Vu Ngoc Tuoc, Nguyen Viet Minh, Pham Nam Phong, and Doan Nhat Quang - Effect of Sheet Polarization Charges on the Electron Mobility in an AlGaIn/GaN Infinitely Deep Quantum Well	29-42
Do Thi Nga, Tran Thi Thanh Van, and Nguyen Ai Viet - On the Exciton Effects in Optical Properties of Single Wall Carbon Nano Tubes	43-49
Tran Thi Thanh Van, Vo Thi Hoa, Nguyen Thi Thanh Hang, and Nguyen Ai Viet - Optical Quantum Computer from Excitons in Coupled Spherical Quantum Dots	50-55
Phung Quoc Vuong, Nguyen Quang Bau, Nguyen Bich Ngoc, and Le Dinh - Parametric Resonance of Acoustic and Optical Phonons in Rectangular Quantum Wires	56-58
Phung Quoc Vuong, Nguyen Quang Bau, and Nguyen Ngoc Hieu - The Influence of Confined Phonons and Electrons on the Absorption Coefficient of a Weak Electromagnetic Wave by Free Electrons in Quantum Wells	59-64

(See cover 4)

90.

DEBYE-WALLER FACTOR AND CORRELATION EFFECTS IN XAFS OF CUBIC CRYSTALS

NGUYEN VAN HUNG, PHUNG QUOC BAO, NGUYEN BA DUC

Department of Physics, Hanoi University of Science

LE HAI HUNG

Institute of Engineering Physics, Hanoi University of Technology

Abstract. Analytical expressions for the Displacement-displacement Correlation Function (DCF) C_R and Debye-Waller factor described by the Mean Square Relative Displacement (MSRD) σ^2 and by the Mean Square Displacement (MSD) u^2 of cubic (fcc, bcc) crystals in the X-ray Absorption Fine Structure (XAFS) have been derived. The effective interatomic potential of the system has been considered by taking into account the influences of nearest atomic neighbors, and it contains the Morse potential characterizing the interaction of each pair of atoms. Numerical calculations have been carried out for u^2 , σ^2 , and C_R functions of Cu (fcc) and W (bcc). The ratio C_R/u^2 is about 40% for fcc and 54% for bcc at high temperatures. They are found to be in good agreement with experiment and with those calculated by the Debye model.

I. INTRODUCTION

It is of great interest in XAFS procedure to characterize the local atomic environment of the substances, i.e., we would in principle like to determine the position, type, and number of the central atoms and their neighbors in a cluster and to determine such interesting properties as the relative vibrational amplitudes and spring constants of these atoms. At any temperature the positions R_j of the atoms are smeared by thermal vibrations. Therefore, in all treatments of XAFS the effect of this vibrational smearing has been included in the XAFS function [1]

$$\chi = \chi_0 \langle e^{2ik\Delta_j} \rangle; \Delta_j = \hat{R}_j^0 \cdot (\mathbf{u} - \mathbf{u}_0), \hat{R} = \mathbf{R}/|\mathbf{R}|, \quad (1)$$

where \mathbf{u}_j and \mathbf{u}_0 are the j th atom and the central-atom displacement, respectively.

This XAFS function (1) contains the thermal averaging value $\langle e^{i2k\Delta_j} \rangle$ leading to the Debye-Waller factor $DWF = e^{-2k^2\sigma_j^2}$. Since this factor is meant to account for the thermal vibrations of the atoms about their equilibrium sites R_j^0 , one usually assumes that the quantity σ_j^2 is identical with the MSD [1]. But the oscillatory motion of nearby atoms is relative. Hence, including the correlation effect in the atomic vibration is necessary [2-9]. In this case σ_j^2 is the MSRD containing the MSD and DCF.

The purpose of this work is to study the correlation effects in atomic vibrations of cubic crystals in XAFS, i.e., to develop a new procedure for calculation of the DCF (C_R) for atomic vibration in the cubic crystals (fcc, bcc) in XAFS. Expression for the MSD (u^2) has been derived. Using it and the MSRD (σ^2) we derive C_R . The effective interaction potential of the system has been considered by taking into account the influences of the

nearest atomic neighbors based on the anharmonic correlated Einstein model [3]. This potential contains the Morse potential characterizing the interaction of each pair of atoms. Numerical calculations have been carried out for Cu (fcc) and W (bcc). The calculated u^2 , σ^2 , C_R functions and the ratio C_R/u^2 , C_R/σ^2 of these crystals are found to be in good agreement with those calculated by the Debye model [2] and with experiment [6, 7, 9].

II. FORMALISM

For perfect crystals with using Eq. (1) the MSD is given by

$$\sigma_j^2 = \langle \Delta_j^2 \rangle = 2u_j^2 - C_R. \quad (2)$$

Here we defined the MSD function as

$$u_j^2 = \langle (u_0 \cdot \hat{R}_j^0)^2 \rangle = \langle (u_j \cdot \hat{R}_j^0)^2 \rangle \quad (3)$$

and the DCF

$$C_R = 2 \langle (u_0 \cdot \hat{R}_j^0)(u_j \cdot \hat{R}_j^0) \rangle = 2u_j^2 - \sigma_j^2. \quad (4)$$

It is clear that all atoms vibrate under influence of the neighboring environment. Taking into account the influences of the nearest atomic neighbors the Einstein effective interatomic potential for single vibrating atom is given by (ignoring the overall constant)

$$U_{eff}^o(x) = \sum_{j=1}^N U(x \hat{R}_{01} \cdot \hat{R}_{0j}); N = \begin{cases} 12, & \text{for fcc,} \\ 8, & \text{for bcc,} \end{cases} \quad (5)$$

$$U_{eff}^o(y) = \frac{1}{2} k_{eff}^o y^2, k_{eff}^o = D\alpha^2 (S_0 - 4\alpha a) = M_0 \omega_E^2, \quad (6)$$

where M_0 is the central atomic mass; D and α are the parameters of the Morse potential

$$U(x) = D(e^{-2\alpha x} - 2e^{-\alpha x}) \cong D(-1 + \alpha^2 x^2 - \alpha^3 x^3 + \dots), \quad (7)$$

and the other parameters have been defined as follows

$$y = x - a, x = r - r_0, a = \langle r - r_0 \rangle, S_0 = \begin{cases} 8, & \text{for fcc} \\ 16/3, & \text{for bcc} \end{cases} \quad (8)$$

with r and r_0 as the instantaneous and equilibrium bond length of absorber and backscatterer.

Using Eqs. (5-8) we obtained the Einstein frequency ω_E^o and temperature θ_E^o

$$\omega_E^o = [D\alpha^2 (S_0 - 4\alpha a)/M_0]^{1/2}, \theta_E^o = \hbar \omega_E^o / k_B, \quad (9)$$

where k_B is Boltzmann constant.

The atomic vibration is quantized as phonon, that is why we express y in terms of annihilation and creation operators, \hat{a} and \hat{a}^+ , i. e.,

$$y \equiv a_0 = (\hat{a} + \hat{a}^+), a_0^2 = \frac{\hbar \omega_E^o}{2k_{eff}^o}, \quad (10)$$

and use the harmonic oscillator state $|n\rangle$ as the eigenstate with the eigenvalue $E_n = n\hbar\omega_E^o$, ignoring the zero-point energy for convenience.

Using the quantum statistical method, where we have used the statistical density matrix Z and the unperturbed canonical partition function ρ_0

$$Z = Tr \rho_0 = \sum_n \exp(-n\beta\hbar\omega_E^0) = \sum_{n=0}^{\infty} z_0^n = \frac{1}{1-z_0}, \beta = 1/k_B T, z_0 = e^{-\theta_E^0/T}, \quad (11)$$

we determined the MSD function

$$\begin{aligned} u^2 &= \langle y^2 \rangle \approx \frac{1}{Z} \sum_n \exp(-n\beta\hbar\omega_E^0) \langle n|y^2|n \rangle \\ &= 2a_0^2(1-z_0) \sum_n (1+n)z_0^n = \frac{\hbar\omega_E^0}{2k_{eff}} \frac{1+z_0}{1-z_0} = \frac{\hbar\omega_E^0}{2S_0D\alpha^2} \frac{1+z_0}{1-z_0} \\ &= u_0^2 \frac{1+z_0}{1-z_0}, \quad u_0^2 = \frac{\hbar\omega_E^0}{2S_0D\alpha^2}. \end{aligned} \quad (12)$$

In the crystal each atom vibrates in the relation to the others so that the correlation must be included. Based on quantum statistical theory with the correlated Einstein model [3] the MSRDF function for fcc and bcc crystals has been calculated and is given by

$$\sigma^2(T) = \sigma_0^2 \frac{1+z}{1-z}, \quad \sigma_0^2 = \frac{\hbar\omega_E}{2SD\alpha^2}; \quad z = e^{-\theta_E/T}; \quad S = \begin{cases} 5, & \text{for fcc} \\ 11/3, & \text{for bcc} \end{cases}, \quad (13)$$

$$\omega_E = \sqrt{\frac{k_{eff}}{\mu}} = \left[\frac{D\alpha^2}{\mu} \left(S - \frac{15}{2}\alpha a \right) \right]^{1/2}; \quad \mu = \frac{M_a M_s}{M_a + M_s}; \quad \theta_E = \frac{\hbar\omega_E}{k_B}, \quad (14)$$

where M_a and M_s are the masses of absorbing and backscattering atoms; and in Eqs. (12), (13), u_0^2 , σ_0^2 are the zero point contributions to u^2 and σ^2 ; ω_E , θ_E are the correlated Einstein frequency and temperature, respectively; S , S_0 are the structural parameters. [8].

From the above results we obtained the DCF C_R , the ratio C_R/u^2 and C_R/σ^2

$$C_R = \frac{2u_0^2(1+z_0)(1-z) - \sigma_0^2(1-z_0)(1+z)}{(1-z_0)(1-z)}, \quad (15)$$

$$\frac{C_R}{u^2} = 2 - \frac{\sigma_0^2(1+z)(1-z_0)}{u_0^2(1-z)(1+z_0)}, \quad (16)$$

$$\frac{C_R}{\sigma^2} = \frac{2u_0^2(1+z)(1-z_0) - \sigma_0^2(1-z_0)(1+z)}{\sigma_0^2(1-z_0)(1+z)}, \quad (17)$$

It is useful to consider the high-temperature (HT) limit, where the classical approach is applicable, and the low temperature (LT) limit, where the quantum theory must be used.

In the HT limit we use the approximation

$$z(z_0) \approx 1 - \hbar\omega_E(\omega_E^0)/k_B \quad (18)$$

to simplify the expressions of the thermodynamic parameters. In the LT limit $z(z_0) \Rightarrow 0$, so that we can neglect $z^2(z_0^2)$ and higher power terms. The results of these limits are written in Table 1.

Table 1. Expressions of u^2 , σ^2 , C_R , C_R/u^2 , C_R/σ^2 in the LT and HT limits

Function	$T \ll 0_E$	$T \gg 0_E$
u^2	$u_0^2(1 + 2z_0)$	$k_B T / S_0 D \alpha^2$
σ^2	$\sigma_0^2(1 + 2z)$	$k_B T / S D \alpha^2$
C_R	$2u_0^2(1 + 2z_0) - \sigma_0^2(1 + 2z)$	$(2S - S_0)k_B T / S S_0 D \alpha^2$
$\frac{C_R}{u^2}$	$2 - \frac{\sigma_0^2(1 + 2z)}{u_0^2(1 + 2z_0)}$	$2 - \frac{S_0}{S} = \begin{cases} 0.04, \text{ fcc} \\ 0.54 \text{ bcc} \end{cases}$
$\frac{C_R}{\sigma^2}$	$2 \frac{u_0^2(1 + 2z_0)}{\sigma_0^2(1 + 2z)} - 1$	$\frac{2S - S_0}{S_0} = \begin{cases} 0.25, \text{ fcc} \\ 0.37 \text{ bcc} \end{cases}$

III. NUMERICAL RESULTS

Now we apply the expressions derived in the previous section to numerical calculations for Cu (fcc) and W (bcc). The Morse potential parameters D and α of these crystals have been calculated by using the procedure presented in [11]. The calculated values of D , α , r_0 , k_{eff}^0 , k_{eff} , ω_E^0 , ω_E , θ_E^0 , θ_E are presented in Table 2. They show a good agreement of our calculated values with experiment [6, 7] and with those calculated by another procedure [12]. The effective spring constants, the Einstein frequencies and temperatures

Table 2. Calculated values of D , α , r_0 , k_{eff}^0 , ω_E^0 , ω_E for Cu (fcc) and W (bcc) compared to experiment [6, 7] and to those of the other procedure [12]

Crystal	D (eV)	α (\AA^{-1})	r_0 (\AA)	k_{eff}^0 (N/m)	k_{eff} (N/m)	ω_E^0 (10^{13} Hz)	ω_E (10^{13} Hz)	θ_E^0 (K)	θ_E (K)
Cu, present	0.337	0.358	2.868	79.66	49.789	2.739	3.063	209.25	233.95
Cu, exp. [6]	0.330	1.380	2.862		50.345		3.082		235.26
Cu, [12]	0.343	1.359	2.866	81.20	50.748	2.766	3.092	211.26	236.20
W, present	0.992	1.411	3.035	168.8	116.03	2.344	2.748	179.01	209.98
W, exp. [7]	0.990	1.440	3.052		120.60		2.803		214.08
W, [12]	0.991	1.412	3.032	168.8	116.07	2.345	2.749	179.11	210.02

change significantly when the correlation is included. The calculated Morse potential compared to experiment [6] for Cu and [7] for W are illustrated in Fig. 1 showing a good agreement with experiment. Fig. 2 shows temperature dependence of the calculated MSD σ^2 of Cu and W compared to their MSD u^2 . The MSD are greater than the MSD especially at high temperature. The temperature dependence of our calculated correlation function (DCF) C_R of Cu and W is illustrated in Fig. 3 and their ratio with the MSD function u^2 in Fig. 4. All they agree well with experiment [6, 7]. The MSD, MSD and DCF are linearly proportional to the temperature at high-temperatures and contain zero point contributions at low-temperatures showing the same properties of these functions obtained by the Debye model [2] and satisfying all standard properties of these quantities [10]. Hence, they show the significance of the correlation effects contributing to the Debye-Waller factor in XAFS. Fig. 4 shows the significance of the correlation effects described by C_R in the atomic vibration influencing on XAFS. At high temperatures it is about 40%

for fcc and 54% for bcc crystals that is the same conclusion resulted by the Debye model. Table 1 shows that the ratio C_R/σ^2 is 25% for fcc and 37% for bcc at high temperatures.

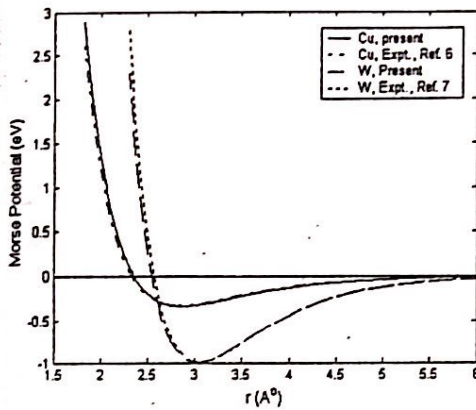


Fig. 1. Calculated Morse potential of Cu and W compared to experiment [6, 7]

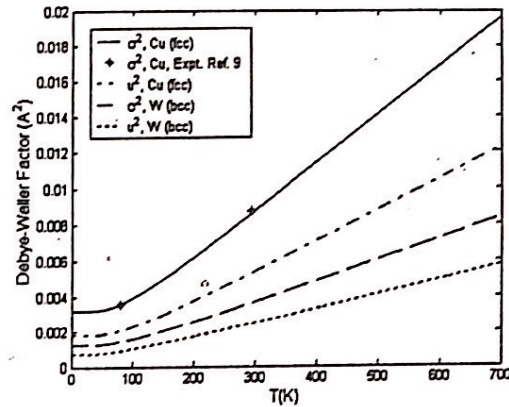


Fig. 2. Temperature dependence of the calculated σ^2 , u^2 for Cu and W compared to experiment [9]

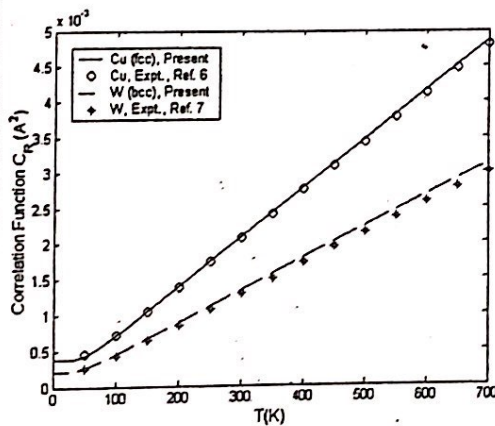


Fig. 3. Temperature dependence of the calculated DCF C_R of Cu and W compared to experiment [6, 7]

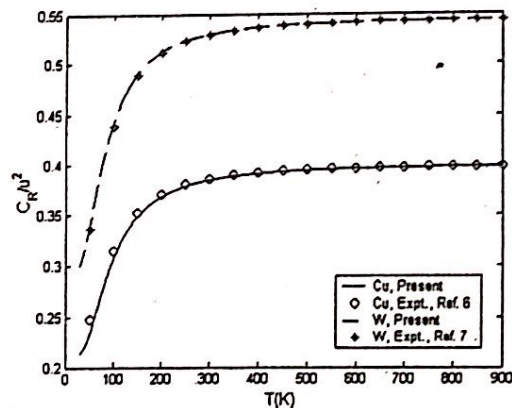


Fig. 4. Temperature dependence of the calculated ratio C_R/u^2 for Cu and W compared to experiment [6, 7]

IV. CONCLUSIONS

In this work a new procedure for studying Debye-Waller factor and correlation effects in the atomic vibration of cubic (fcc, bcc) crystals in XAFS has been developed.

Derived functions C_R , u^2 , σ^2 are linearly proportional to temperature at high-temperatures and contain zero-point contributions at low temperatures. The ratio C_R/u^2 accounts for 40% for fcc and 53% for bcc crystals, the ratio C_R/σ^2 is 25% for fcc and 37% for bcc at high-temperatures showing the significance of correlation effects in the atomic vibration of crystals.

Good agreement of our calculated functions with experiment and with those obtained by the Debye model denotes a new procedure for study of Debye-Waller and of the atomic correlated vibration in XAFS theory.

ACKNOWLEDGMENT

This work is supported in part by the basic science research project No. 41.10.04 and the special research project No. QG.05.04 of VNU Hanoi.

REFERENCES

- [1] C. A. Ashley and S. Doniach, *Phys. Rev. B* 10 (1975) 3027.
- [2] G. Beni and P. M. Platzman, *Phys. Rev. B* 14 (1976) 1514.
- [3] N. V. Hung and J. J. Rehr, *Phys. Rev. B* 56 (1997) 43.
- [4] N. V. Hung, N. B. Duc, and R. R. Frahm, *J. Phys. Soc. Jpn.*, 72 (2003) 1254.
- [5] M. Daniel, D. M. Pease, N. V. Hung, and J. I. Budnick, *Phys. Rev. B* 69 (2004) 134414.
- [6] I. V. Pirog and T. I. Nedoseikina, *Physica B* 334 (2003) 123.
- [7] I. V. Pirog, T. I. Nedoseikina, I. A. Zarubin, and A. T. Shuvaev, *J. Phys.: Condens. Matter*, 14 (2002) 1825.
- [8] N. V. Hung, N. B. Duc, and D. Q. Vuong, *Comm. in Phys.* 11 (2001) 1.
- [9] T. Yokoyama, T. Satsukawa, and T. Ohta, *Jpn. J. Appl. Phys.*, 28 (1989) 1905.
- [10] J. M. Ziman, *Principle of the Theory of Solids*, 2nd ed. by Cambridge University Press, 1972.
- [11] N. V. Hung, *Comm. in Phys.* 14 (2004) 7.
- [12] L. A. Girifalco and V. G. Weizer, *Phys. Rev.*, 114 (1959) 687.